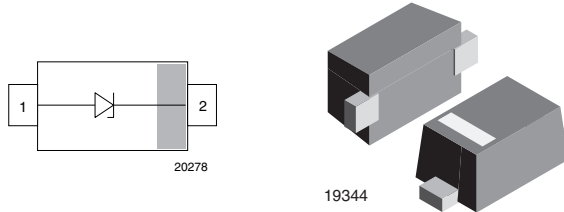


Single ESD-Protection Diode in SOD-523



FEATURES

- Single-line ESD-protection
- Low leakage current
- ESD-immunity acc. IEC 61000-4-2
± 8 kV contact discharge
± 15 kV air discharge
- e3 - Sn
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC



MARKING (example only)



Bar = cathode marking

X = date code

Y = type code (see table below)

ORDERING INFORMATION

DEVICE NAME	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY
VESD01-02V	VESD01-02V-G-08	3000	3000
VESD03-02V	VESD03-02V-G-08	3000	3000
VESD05-02V	VESD05-02V-G-08	3000	3000
VESD08-02V	VESD08-02V-G-08	3000	3000
VESD12-02V	VESD12-02V-G-08	3000	3000

PACKAGE DATA

DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD01-02V	SOD-523	.V	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD03-02V	SOD-523	.B	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD05-02V	SOD-523	.C	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD08-02V	SOD-523	.D	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals
VESD12-02V	SOD-523	.E	1.4 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	260 °C/10 s at terminals

** Please see document "Vishay Material Category Policy": www.vishay.com/doc?99902

ABSOLUTE MAXIMUM RATINGS VESD01-02V				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	acc. IEC 61000-4-5, 8/20 μ s/single shot	I_{PPM}	7	A
Peak pulse power	acc. IEC 61000-4-5, 8/20 μ s/single shot	P_{PP}	63	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}$ C
Storage temperature		T_{stg}	- 55 to + 150	$^{\circ}$ C

ABSOLUTE MAXIMUM RATINGS VESD03-02V				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	acc. IEC 61000-4-5, 8/20 μ s/single shot	I_{PPM}	9	A
Peak pulse power	acc. IEC 61000-4-5, 8/20 μ s/single shot	P_{PP}	108	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}$ C
Storage temperature		T_{stg}	- 55 to + 150	$^{\circ}$ C

ABSOLUTE MAXIMUM RATINGS VESD05-02V				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	acc. IEC 61000-4-5, 8/20 μ s/single shot	I_{PPM}	6	A
Peak pulse power	acc. IEC 61000-4-5, 8/20 μ s/single shot	P_{PP}	120	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}$ C
Storage temperature		T_{stg}	- 55 to + 150	$^{\circ}$ C

ABSOLUTE MAXIMUM RATINGS VESD08-02V				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	acc. IEC 61000-4-5, 8/20 μ s/single shot	I_{PPM}	4	A
Peak pulse power	acc. IEC 61000-4-5, 8/20 μ s/single shot	P_{PP}	120	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}$ C
Storage temperature		T_{stg}	- 55 to + 150	$^{\circ}$ C

ABSOLUTE MAXIMUM RATINGS VESD12-02V				
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	acc. IEC 61000-4-5, 8/20 μ s/single shot	I_{PPM}	2	A
Peak pulse power	acc. IEC 61000-4-5, 8/20 μ s/single shot	P_{PP}	25	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V_{ESD}	± 8	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		± 15	kV
Operating temperature	Junction temperature	T_J	- 40 to + 125	$^{\circ}$ C
Storage temperature		T_{stg}	- 55 to + 150	$^{\circ}$ C

**ELECTRICAL CHARACTERISTICS VESD01-02V**

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_{R\text{max}}$	V_{RWM}	1	-	-	V
Reverse current	at V_{RWM}	I_R	-	-	100	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	1.5	-	-	V
Reverse clamping voltage	at I_{PP} (see fig. 1)	V_C	-	9	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	180	-	pF

ELECTRICAL CHARACTERISTICS VESD03-02V

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_{R\text{max}}$	V_{RWM}	3	-	-	V
Reverse current	at V_{RWM}	I_R	-	-	20	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	4	-	-	V
Reverse clamping voltage	at I_{PP} (see fig. 1)	V_C	-	12	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	110	-	pF

ELECTRICAL CHARACTERISTICS VESD05-02V

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_{R\text{max}}$	V_{RWM}	5	-	-	V
Reverse current	at V_{RWM}	I_R	-	-	0.1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	6.5	-	-	V
Reverse clamping voltage	at I_{PP} (see fig. 1)	V_C	-	20	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	55	-	pF

ELECTRICAL CHARACTERISTICS VESD08-02V

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_{R\text{max}}$	V_{RWM}	8	-	-	V
Reverse current	at V_{RWM}	I_R	-	-	0.1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	9	-	-	V
Reverse clamping voltage	at I_{PP} (see fig. 1)	V_C	-	30	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	35	-	pF

ELECTRICAL CHARACTERISTICS VESD12-02V

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N_{channel}	-	-	1	lines
Reverse working voltage	at $I_{R\text{max}}$	V_{RWM}	12	-	-	V
Reverse current	at V_{RWM}	I_R	-	-	0.1	μA
Reverse breakdown voltage	at $I_R = 1 \text{ mA}$	V_{BR}	14	-	-	V
Reverse clamping voltage	at I_{PP} (see fig. 1)	V_C	-	25	-	V
Capacitance	at $V_R = 0 \text{ V}$; $f = 1 \text{ MHz}$	C_D	-	30	-	pF

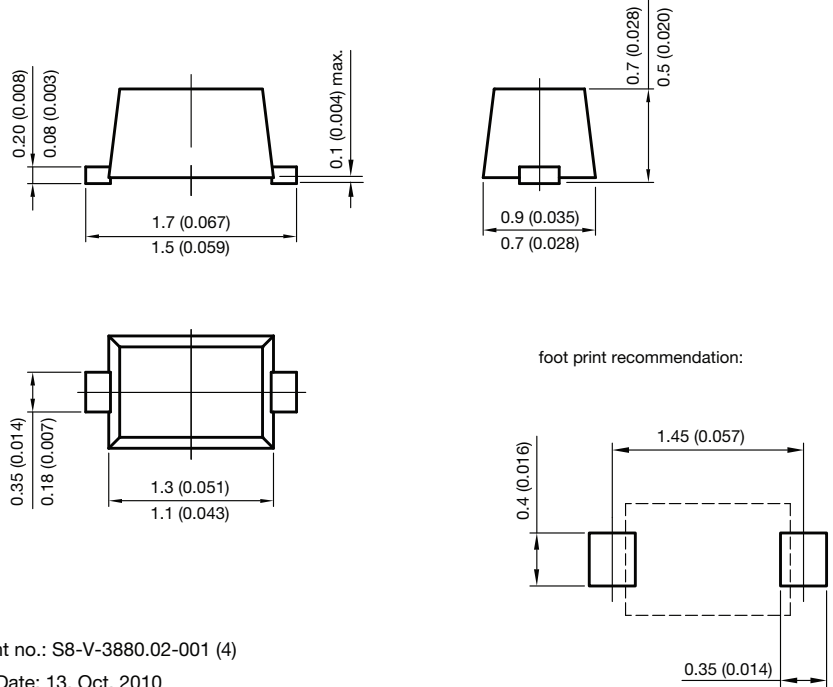
VESDxx-02V

Vishay Semiconductors

Single ESD-Protection Diode in
SOD-523



PACKAGE DIMENSIONS in millimeters (inches): **SOD-523**



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